

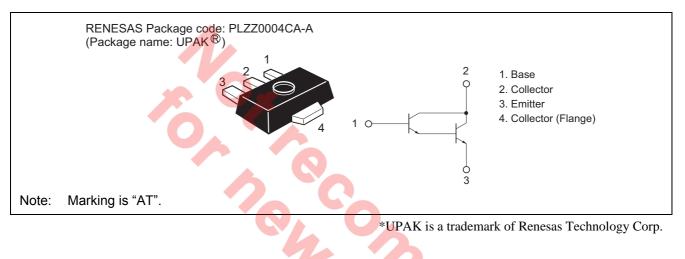
# **2SD1470** Silicon NPN Epitaxial, Darlington

REJ03G0791-0200 (Previous ADE-208-1153) Rev.2.00 Aug.10.2005

### Application

Low frequency power amplifier

### Outline



# **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Collector to base voltage	V <sub>CBO</sub>	60	V
Collector to emitter voltage	V <sub>CEO</sub>	60	V
Emitter to base voltage	V <sub>EBO</sub>	7	V
Collector current	I <sub>C</sub>		A
Collector peak current	i <sub>C(peak)</sub> * <sup>1</sup>	2	A
Collector power dissipation	Pc*2	1	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	–55 to +150	°C

Notes: 1.  $PW \le 10 \text{ ms}$ ,  $Duty cycle \le 20\%$ 

2. Value on the alumina ceramic board (12.5 x 30 x 0.7 mm)



# **Electrical Characteristics**

(Ta = 25°C)

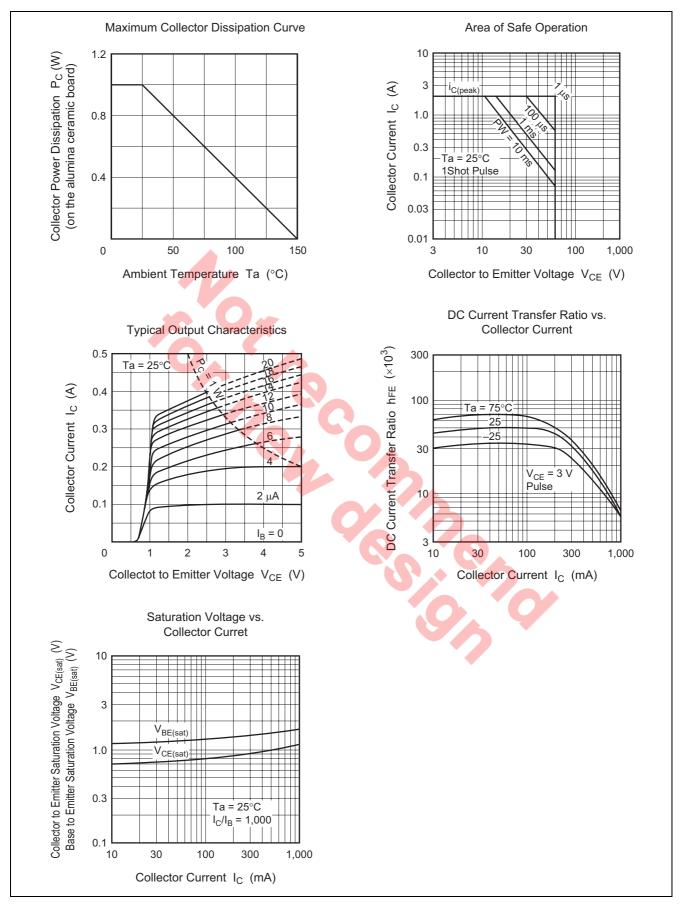
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	V <sub>(BR)CBO</sub>	60	_	—	V	$I_{\rm C}$ = 10 $\mu$ A, $I_{\rm E}$ = 0
Collector to emitter breakdown voltage	V <sub>(BR)CEO</sub>	60	_	—	V	I <sub>C</sub> = 1 mA, R <sub>BE</sub> = ∞
Emitter to base breakdown voltage	V <sub>(BR)EBO</sub>	7		—	V	I <sub>E</sub> = 10 μA, I <sub>C</sub> = 0
Collector cutoff current	I <sub>CBO</sub>	_	_	10	μA	$V_{CB} = 60 \text{ V}, \text{ I}_{E} = 0$
Emitter cutoff current	I <sub>EBO</sub>	_	_	10	μA	$V_{EB} = 7 V, I_{C} = 0$
DC current transfer ratio	h <sub>FE</sub>	2000	_	100000		V <sub>CE</sub> = 3 V, I <sub>C</sub> = 0.5 A* <sup>1</sup>
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	_	1.5	V	$I_{\rm C}$ = 500 mA, $I_{\rm B}$ = 0.5 mA* <sup>1</sup>
Base to emitter saturation voltage	V <sub>BE(sat)</sub>	_	_	2.0	V	$I_{\rm C}$ = 500 mA, $I_{\rm B}$ = 0.5 mA* <sup>1</sup>

Notes: 1. Pulse test

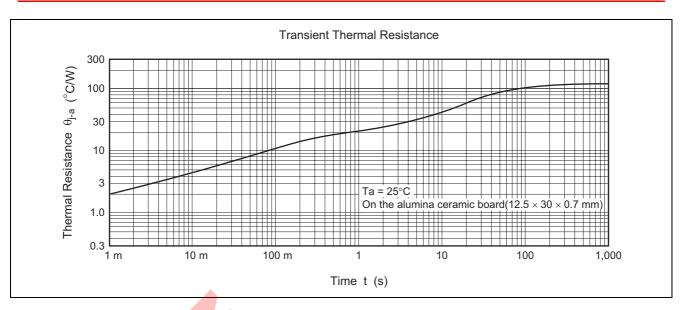




### **Main Characteristics**

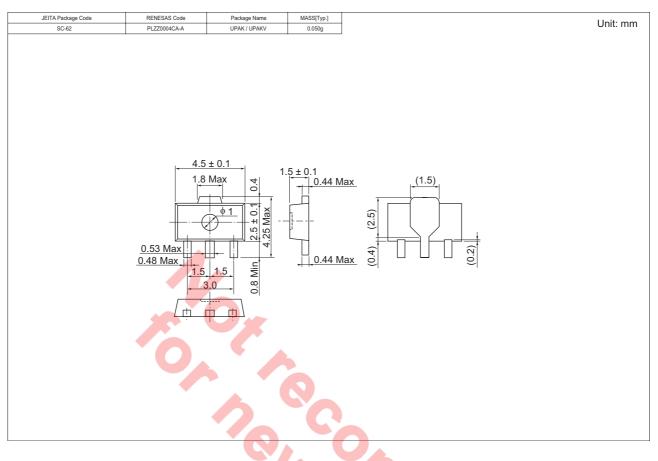








## **Package Dimensions**



### **Ordering Information**

Part Name	Quantity	Shipping Container
2SD1470ATTR-E	1000	

\*\*,

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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